



A Product Line of Diodes Incorporated



FMMT491

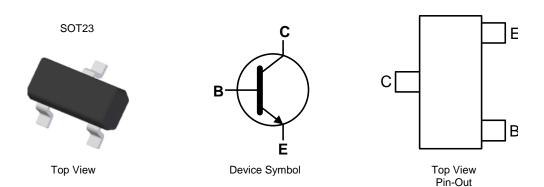
60V NPN MEDIUM POWER TRANSISTOR IN SOT23

Feature

- BV_{CEO} > 60V
- I_C = 1A Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- $R_{CE(sat)} = 195m\Omega$ for a Low Equivalent On-Resistance
- 500mW Power Dissipation
- hFE Characterized up to 2A for High Current Gain Hold up
- Complementary PNP Type: FMMT591
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded plastic, "Green" Molding Compound
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 (€3)
- Weight 0.008 grams (Approximate)



Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT491TA	AEC-Q101	491	7	8	3,000
FMMT491TC	AEC-Q101	491	13	8	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information









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Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ι _C	1	А
Peak Pulse Current	I _{CM}	2	А
Base Current	IB	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ ext{ heta}JA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)	R _θ JL	197	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state.

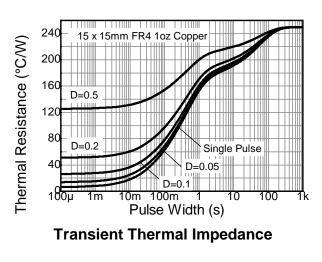
6. Thermal resistance from junction to solder-point (at the end of the collector lead).

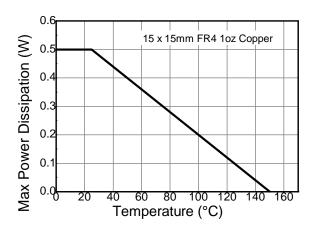
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



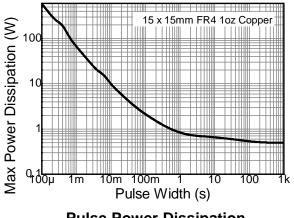


Thermal Characteristics and Derating Information





Derating Curve



Pulse Power Dissipation





FMMT491

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

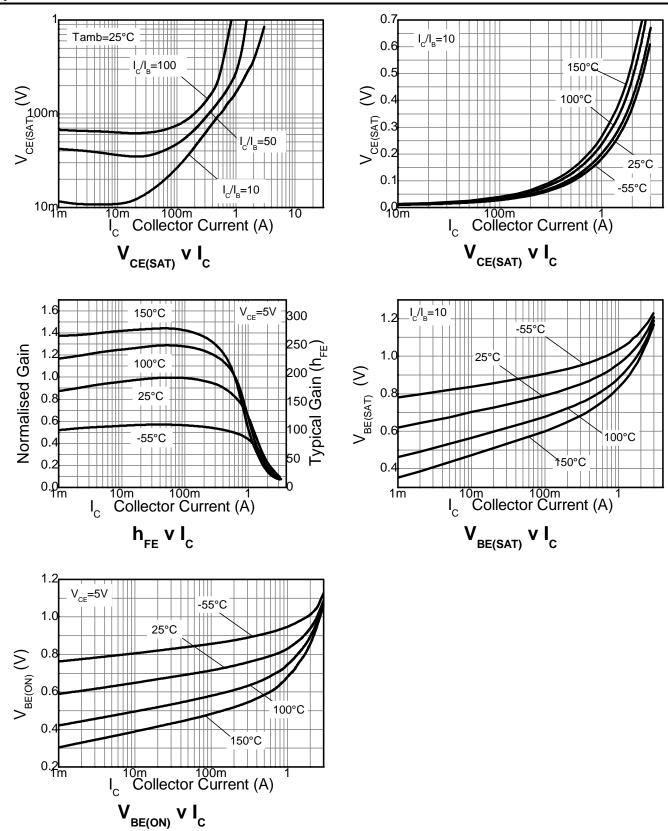
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВV _{CBO}	80	_	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	60	_	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	_	V	I _E = 100μA
Collector Cutoff Current	I _{СВО}		<1	100	nA	V _{CB} = 60V
Emitter Cutoff Current	I _{EBO}	—	<1	100	nA	V _{EB} = 5.6V
Collector Emitter Cutoff Current	I _{CES}	—	<1	100	nA	$V_{CE} = 60V, V_{CES} = 60V$
	hFE	100	140	—		$I_{C} = 1 m A, V_{CE} = 5 V$
		100	150	300	_	I _C = 500mA, V _{CE} = 5V
Static Forward Current Transfer Ratio (Note 8)		80	120	_		I _C = 1A, V _{CE} = 5V
		30	40	_		$I_{C} = 2A, V_{CE} = 5V$
Collector Emitter Seturation Voltage (Note 9)	V _{CE(sat)}	_	100	150	m)/	$I_{\rm C} = 500$ mA, $I_{\rm B} = 50$ mA
Collector-Emitter Saturation Voltage (Note 8)			160	250	mV	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA
Base-Emitter Turn-On Voltage(Note 8)	V _{BE(on)}	—	830	1000	mV	I _C = 1A, V _{CE} = 5V
Base-Emitter Saturation Voltage(Note 8)	V _{BE(sat)}	_	965	1100	mV	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA
Output Capacitance	C _{obo}	—	_	10	pF	V _{CB} = 10V, f = 1MHz
Transition Frequency	f _T	150	_	_	MHz	$V_{CE} = 10V, I_C = 50mA,$ f = 100MHz

8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%. Note:





Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

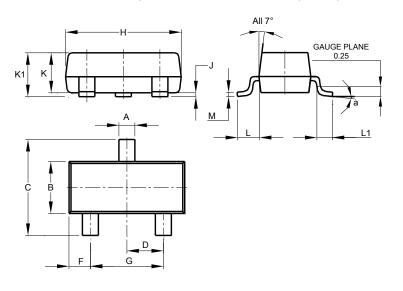






Package Outline Dimensions

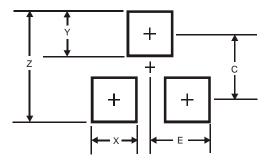
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	8°				
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Y	0.9		
С	2.0		
E	1.35		





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